Power Products Division

Advance Information

3-HIGH SIDE & **3-LOW SIDE DRIVER**

The MPIC2131 is a high voltage, high speed, power MOSFET and IGBT driver with three independent high side and low side referenced output channels for 3-Phase applications. Proprietary HVIC technology enables ruggedized monolithic construction. Logic inputs are compatible with 5 V CMOS or LSTTL outputs. A ground referenced operational amplifier provides an analog feedback of bridge current via an external current sense resistor. A current trip function which terminates all six outputs is also derived from an external current sense resistor. An extra shutdown input is provided for customizing the shutdown function. An open drain FAULT signal is provided to indicate that any of shutdown conditions has occurred. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. Propagation delays are matched to simplify use in high frequency applications.

The floating channels can be used to drive N-channel power MOSFET or IGBT's in the high side configuration which operate from 10 to 600 volts.

- Floating Channel Designed for Bootstrap Operation
- Fully Operational to +600 V
- Tolerant to Negative Transient Voltage
- dV/dt Immune
- Gate Drive Supply Range from 10 to 20 V
- Undervoltage Lockout for All Channels
- Over-current Shut Down Turns Off All Six Drivers
- Independent 3 High Side & 3 Low Side Drivers
- Matched Propagation Delay for All Channels
- Outputs Out of Phase with Inputs

PRODUCT SUMMARY

VOFFSET **600 V MAX** 10+/-200 mA/420 mA

VOUT 10 - 20 V ton/off (typical) 1.4 & 0.7 μs **Delay Matching** 700 ns

MPIC2131

by MPIC2131/D

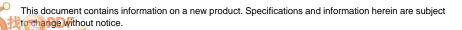
3 HIGH SIDE & 3 LOW SIDE **DRIVER**



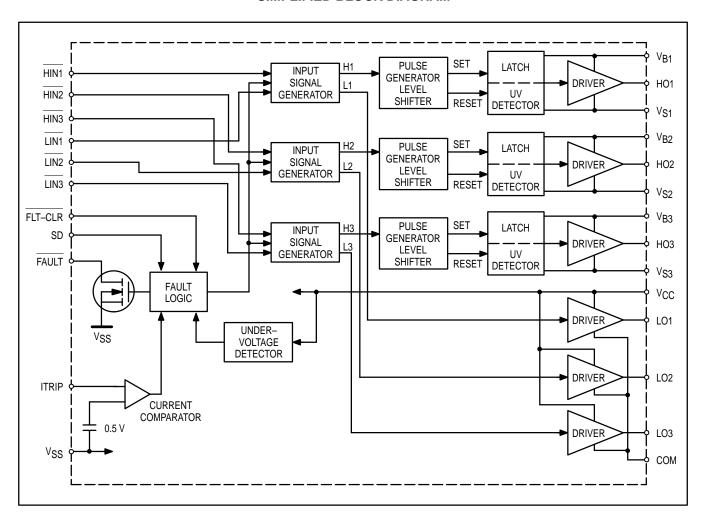


ORDERING INFORMATION

Device	Package
MPIC2131P	PDIP



SIMPLIFIED BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The Thermal Resistance and Power Dissipation ratings are measured under board mounted and still air conditions.

Rating	Symbol	Min	Max	Unit
High Side Floating Absolute Voltage High Side Floating Supply Offset Voltage High Side Floating Output Voltage Low Side Output Voltage Fixed Supply Voltage Fixed Supply Offset Voltage Logic Input Voltage (HIN-, LIN-, FLT-, CLR-, SD & ITRIP) Fault Output Voltage	VB1,2,3 VS1,2,3 VHO1,2,3 VLO1,2,3 VCC VSS VIN FAULT	-0.3 VB1,2,3-25 VS1,2,3-0.3 -0.3 -0.3 VCC-25 VSS-0.3 VSS-0.3	625 VB1,2,3+0.3 VB1,2,3+0.3 VCC+0.3 25 VCC+0.3 VCC+0.3 VCC+0.3	VDC
Allowable Offset Supply Voltage Transient	dVg/dt	-	50	V/ns
*Package Power Dissipation @ T _C ≤ +25°C (28 Lead DIP)	PD	_	1.5	Watt
Operating and Storage Temperature	T _j , T _{stg}	-55	150	°C
Thermal Resistance, Junction to Ambient (8 Lead DIP)	$R_{ heta JA}$	_	83	°C/W
Lead Temperature for Soldering Purposes, 10 seconds	TL	_	260	°C

RECOMMENDED OPERATING CONDITIONS

The Input/Output logic timing Diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. The V_S offset rating is tested with all supplies biased at 15 V differential.

High Side Floating Supply Absolute Voltage	V _{B1,2,3}	V _{S1,2,3} +10	V _{S1,2,3} +20	V
High Side Floating Supply Offset Voltage	V _{S1,2,3}	Note 1	V _{SO} +600	V
High Side Floating Output Voltage	VHO1,2,3	VS1,2,3	V _{B1,2,3}	V
Fixed Supply Voltage	Vcc	10	20	V
Low Side Output Voltage	VLO1,2,3	0	VCC	V
Low Side Driver Return	VSS	-5	5	V
Logic Input Voltage (HIN-, LIN-, FLT-CLR, SD & ITRIP)	VIN	VSS	5	V
Fault Output Voltage	FAULT-	VSS	Vcc	V
Ambient Temperature	TA	-40	125	°C

Note 1: Logic operational for Vs of –5 V to +600 V. Logic state held for Vs of –5 V to –Vbs.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise specified)

Characteristic Symbol Min Typ Max Unit
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STATIC ELECTRICAL CHARACTERISTICS

 V_{BIAS} (V_{CC} , $V_{BS1,2,3}$) = 15 V and V_{SS} = COM unless otherwise specified. The V_{IN} , V_{TH} and I_{IN} parameters are referenced to V_{SS} and are applicable to all six channels (HS1,2,3 & LS1,2,3). The VO and IO parameters are referenced to COM and $V_{SO1,2,3}$ and are applicable to the respective output leads: HO1,2,3 or LO1,2,3.

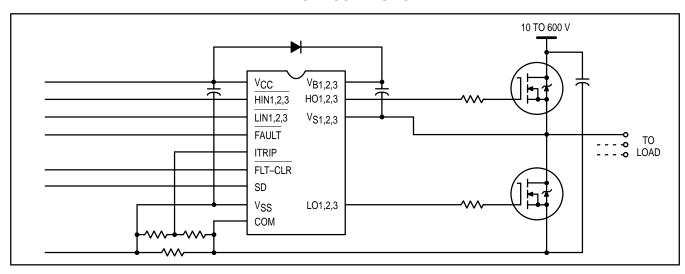
110 100p001110 041p41 10440. 110 1,2,0 01 20 1,2,0.					
Logic "0" Input Voltage (OUT = LO)	VIH	2.2	-	_	V
Logic "1" Input Voltage (OUT = HI)		_	-	0.8	V
Logic "0" Fault Clear Input Voltage		2.2	-	-	V
Logic "1" Fault Clear Input Voltage	V _{FCLR,IL}	-	-	0.8	V
SD Input Positive Going Threshold	V _{SD,TH+}	-	1.8	-	V
SD Input Negative Going Threshold	V _{SD,TH} _	_	1.5	-	V
ITRIP Input Positive Going Threshold	VIT,TH+	-	485	_	mV
ITRIP Input Negative Going Threshold	VIT,TH-	_	400	_	mV
High Level Output Voltage, V _{BIAS} -V _O @ V _{IN} = 0 V, I _O = 0 A	Voн	-	-	100	mV
Low Level Output Voltage, V _O @ V _{IN} = 5 V, I _O = 0 A	VOL	-	-	100	mV
Offset Supply Leakage Current @ VB1,2,3 = VS1,2,3 = 600 V	ILK	-	-	50	μА
Quiescent V _{BS} Supply Current @ V _{IN} = 0 V or 5 V	IQBS	-	30	_	μА
Quiescent V _{CC} Supply Current @ V _{IN} = 0 V or 5 V	IQCC	_	3.0	_	mA
Logic "1" Input Bias Current (OUT = HI) @ V _{IN} = 0 V	I _{IN+}	_	190	_	μА
Logic "0" Input Bias Current (OUT = LO) @ V _{IN} = 5 V	I _{IN} _	_	100	_	μА
"High" ITRIP Bias Current @ ITRIP = 5 V	I _{TRIP+}	-	60	-	μА
"Low" ITRIP Bias Current @ ITRIP = 0 V	I _{TRIP} _	-	-	50	nA
Logic "1" Fault Clear Bias Current @ FLT-CLR = 0 V	I _{FCLR+}	_	190	-	μА
Logic "0" Fault Clear Bias Current @ FLT-CLR = 5 V	I _{FCLR} -	_	100	-	μА
Logic "1" Shut Down Bias Current @ SD = 5 V	I _{SD+}	_	60	-	μА
Logic "0" Shut Down Bias Current @ SD = 5 V	I _{SD} _	_	-	150	nA
V _{BS} Supply Undervoltage Positive Going Threshold	V _{BSUV+}	_	8.6	-	V
V _{BS} Supply Undervoltage Negative Going Threshold		_	8.2	-	V
V _{CC} Supply Undervoltage Positive Going Threshold		_	9.0	-	V
V _{CC} Supply Undervoltage Negative Going Threshold	VCCUV-	_	8.7	-	V
FAULT – Low On Resistance	R _{on,FLT}	-	55	-	Ω
Output High Short Circuit Pulsed Current @ V_{Out} = 0 V, V_{in} = 0 V, PW \leq 10 μs	IO+	200	250	_	mA
Output Low Short Circuit Pulsed Current @ V_{out} = 15 V, V_{in} = 5 V, PW \leq 10 μs	10-	420	500	_	mA

MPIC2131

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise specified)

Characteristic	Symbol	Min	Тур	Max	Unit	
DYNAMIC ELECTRICAL CHARACTERISTICS V_{BIAS} (V_{CC} , $V_{BS1,2,3}$) = 15 V, $V_{SO1,2,3}$ = V_{SS} and V_{CL} = 1000 pF unless otherwise specified. V_{CC} = 25°C.						
Turn-On Propagation Delay @ VIN = 0 & 5 V, VS1,2,3 = 0 V to 600 V	_	1.4	_	μs		
Turn-Off Propagation Delay @ V _{IN} = 0 & 5 V, V _{S1,2,3} = 0 V to 600 V	toff	-	0.7	-	μs	
Turn-On Rise Time @ V _{IN} = 0 & 5 V, V _{S1,2,3} = 0 V to 600 V	t _r	_	80	-	ns	
Turn-On Fall Time @ V _{IN} = 0 & 5 V, V _{S1,2,3} = 0 V to 600 V	tf	_	40	-	ns	
ITRIP to Output Shutdown Propagation Delay @ VIN, VITRIP = 0 & 5 V	titrip	_	550	-	ns	
ITRIP Blanking Time @ ITRIP = 1 V		_	400	_	ns	
ITRIP to FAULT- Propagation Delay @ VIN, VITRIP = 0 & 5 V	tflt	_	450	_	ns	
Input Filter Time (all six inputs) @ V _{IN} = 0 & 5 V		_	310	_	ns	
FLT-CLR to FAULT Clear Time @ V _{IN} , V _{IT} , V _{FC} = 0 & 5 V		_	450	_	ns	
SD to OUTPUT Shutdown Propagation Delay @ V _{IN} , V _{SD} = 0 & 5 V		_	550	_	ns	
Deadtime, LS Turn–Off to HS Turn–On & HS Turn–Off to LS Turn–On @ V _{IN} = 0 & 5 V	DT	-	700	_	ns	

TYPICAL CONNECTION



LEAD DEFINITIONS

Symbol	Lead Description
HIN1,2,3	Logic Inputs for High Side Gate Driver Outputs (HO1,2,3), Out of Phase
LIN1,2,3	Logic Inputs for Low Side Gate Driver Outputs (LO1,2,3), Out of Phase
FLT-CLR	Logic Inputs for Fault Clear
SD	Logic Input for Shut Down
FAULT	Indicates Over–current, Shut Down or Low Side Undervoltage Condition, Negative Logic
ITRIP	Input for Over-current Shut Down
V _{SS}	Logic Ground
V _{B1,2,3}	High Side Floating Supplies
HO1,2,3	High Side Gate Drive Outputs
V _{S1,2,3}	High Side Floating Supply Returns
Vcc	Logic and Low Side Fixed Supply
LO1,2,3	Low Side Gate Drive Outputs
СОМ	Low Side Return

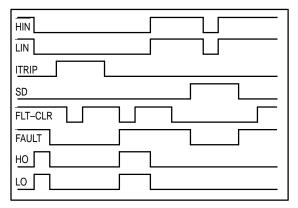


Figure 1. Input / Output Timing Diagram

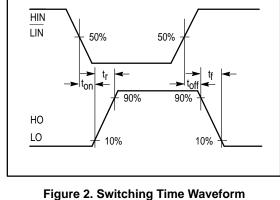


Figure 2. Switching Time Waveform Definitions

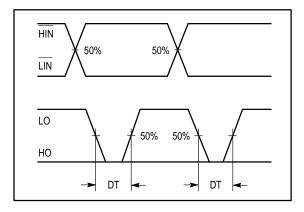


Figure 3. Deadtime Waveform Definitions

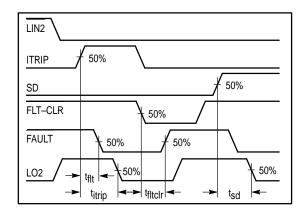
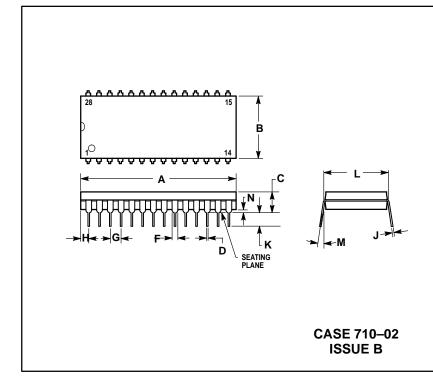


Figure 4. Shutdown Waveform Definitions

PACKAGE DIMENSIONS



NOTES:

- 1. POSITIONAL TOLERANCE OF LEADS (D), SHALL BE WITHIN 0.25 (0.010) AT MAXIMUM MATERIAL CONDITION, IN RELATION TO SEATING PLANE AND EACH OTHER.

 2. DIMENSION L TO CENTER OF LEADS WHEN
- FORMED PARALLEL.

 3. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

	MILLIN	MILLIMETERS		HES		
DIM	MIN	MAX	MIN	MAX		
Α	36.45	37.21	1.435	1.465		
В	13.72	14.22	0.540	0.560		
С	3.94	5.08	0.155	0.200		
D	0.36	0.56	0.014	0.022		
F	1.02	1.52	0.040	0.060		
G	2.54	BSC	0.100 BSC			
Н	1.65	2.16	0.065	0.085		
J	0.20	0.38	0.008	0.015		
K	2.92	3.43	0.115	0.135		
L	15.24	BSC	0.600 BSC			
M	0°	15°	0 °	15°		
N	0.51	1.02	0.020	0.040		

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